

UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : 6,921,692 B2  
DATED : July 26, 2005  
INVENTOR(S) : Kunal R. Parekh et al.

Page 1 of 2

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page.

Item [56], **References Cited**, U.S. PATENT DOCUMENTS,  
delete "6,458, 859 B2 10/2002 Hayashida et al." and insert  
-- 6,468,859 B2 10/2002 Hayashida et al. --.

Column 4.

Line 36, replace "of example only, layer 54 might be formed to to provide a" with  
-- of example only, layer 54 might be formed to provide a --.

Line 40, replace "layer 54 include conductive metal suicides (whether" with  
-- layer 54 include conductive metal silicides (whether --.

Column 7.

Line 17, replace "The method of claim 13 wherein the sacrificial" with  
-- The method of claim 17 wherein the sacrificial --.

Line 60, replace "plugging material with in the bit node contact opening"  
with -- plugging material within the bit mode contact opening --.

Line 66, replace "The method of claim 23 wherein the forming or the" with  
-- The method of claim 23 wherein the forming of the --.

Column 9.

Line 52, replace "plagiarizing sacrificial plugging material." with  
-- planarizing sacrificial plugging material. --.

Column 10.

Line 13, replace "plagiarizing sacrificial plugging material."  
with -- planarizing sacrificial plugging material. --.

Line 27, replace "outer material Selectively to the etch stop material."  
with -- outer material selectively to the etch stop material. --.

Line 47, replace "plagiarizing sacrificial plugging material."  
with -- planarizing sacrificial plugging material. --.

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Page 2 of 2

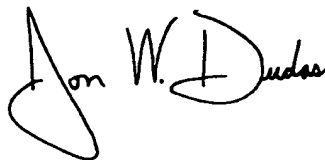
It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 10, (cont'd).

Line 53, replace "node, the capacitor node, the first node, arid the second node." with  
-- node, the capacitor node, the first node, and the second node. --.

Signed and Sealed this

Twenty-third Day of May, 2006

A handwritten signature in black ink, appearing to read "Jon W. Dudas". The signature is stylized with a large, looped initial "J" and a cursive "Dudas".

JON W. DUDAS  
*Director of the United States Patent and Trademark Office*